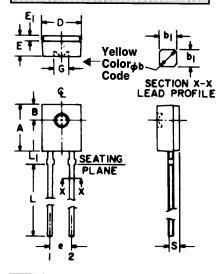


PLASTIC SILICON PHOTODARLINGTON

L14R1

PACKAGE DIMENSIONS



SYMBOL	MILLIMETERS		INC	NOTES	
O I I I I I	MIN.	MAX.	MIN.	MAX.	INOILS
A	5.59	5.80	.220	.228	
В	1.78	NOM.	.070	NOM.	2
® b	.60	.75	.024	.030	1
b₁	.51	NOM.	.020	NOM.	1
D	4.45	4.70	.175	.185	
E	2.41	2.67	.095	.105	
Ε,	.58	.69	.023	.027	
e	2.41	2.67	.095	.105	3
G	1.98	NOM.	.078	NOM.	
۲	12.7		.500	_	
L,	1.40	1.65	.055	.065	
S	.83	.94	.033	.037	3

DESCRIPTION

The L14R1 is a silicon photodarlington encapsulated in a clear, wide angle, sidelooker package.

FEATURES

- Good optical to mechanical alignment
- Mechanically and wavelength matched to the F5F LED
- Plastic package with a color stripe for easy recognition from LED

ST1335

PACKAGE OUTLINE



ST1608

NOTES:

- TWO LEADS. LEAD CROSS SECTION DIMENSIONS
 UNCONTROLLED WITHIN 1.27mm (.050") OF SEATING PLANE.
- SEATING PLANE.

 2. CENTERLINE OF ACTIVE ELEMENT LOCATED WITHIN .25mm (.010") OF TRUE POSITION.

 3. AS MEASURED AT THE SEATING PLANE.

 4. INCH DIMENSIONS DERIVED FROM MILLIMETERS.



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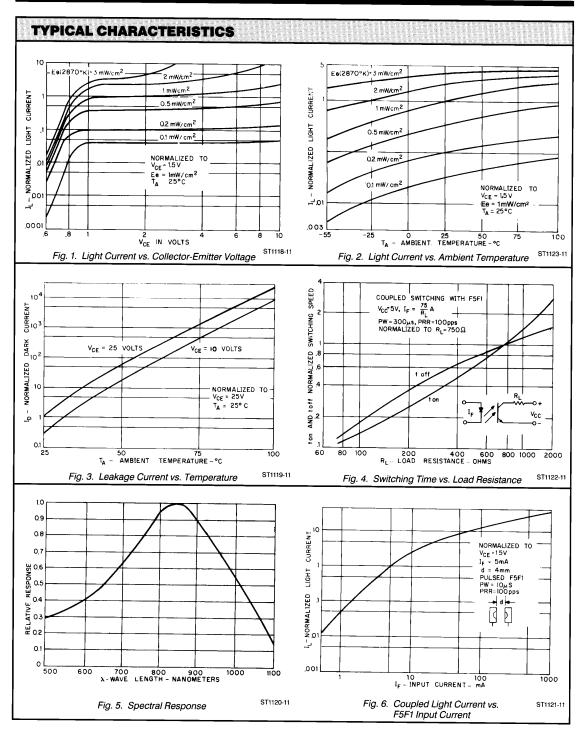
ABSOLUTE MAXIMUM RATINGS (T _A = 25°C Unite	ss Otherwise Specified)
Storage Temperature	
Soldering: Lead Temperature (Iron) Lead Temperature (Flow)	
Collector-Emitter Breakdown Voltage Emitter-Collector Breakdown Voltage Power Dissipation	7 Volts

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Collector-Emitter Breakdown	BV _{CEO}	30		_	V	I _c = 10 mA, Ee = 0
Emitter-Collector Breakdown	BV _{ECO}	7.0		_	V	$I_E = 100 \ \mu\text{A}, Ee = 0$
Collector-Emitter Leakage	I _{CEO}	_		100	nA	V _{CE} = 25, Ee = 0
Reception Angle at ½ Sensitivity	Θ		±35		Degrees	
On-State Collector Current	I _{C(ON)}	5.0		_	mA	$Ee = 0.3 \text{ mW/cm}^2, V_{CE} = 1.5 \text{ V}^{(6)}$
Turn-On Time	t _{on}		45		μS	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 750 \text{ m}$
Turn-Off Time	t _{off}		250		μS	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 750 \text{ M}$
Saturation Voltage	V _{CE(SAT)}	_		1.2	V	$I_c = 20 \text{ mA}, Ee = .60 \text{ mW/cm}^{2(6)}$

NOTES

- 1. Derate power dissipation linearly 2.00mW/°C above 25°C ambient.
- 2. RMA flux is recommended.
- Methanol or Isopropyl alcohols are recommended as cleaning agents.
 Soldering iron tip 1/6" (1.6 mm) minimum from housing.
- 5. As long as leads are not under any stress or spring tension.
- 6. Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.
- 7. Figure 1 and figure 2 use light source of tungsten lamp at 2870°K color temperature. A GaAs source of 3.0 mW/cm² is approximately equivalent to a tungsten source, at 2870°K, of 10 mW/cm².







HERMETIC SILICON PHOTODARLINGTON

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.